

APT2012SF4C-PRV

2.0 x 1.25 mm Infrared Emitting Diode



DESCRIPTION

 SF4 Made with Gallium Aluminum Arsenide Infrared Emitting diodes

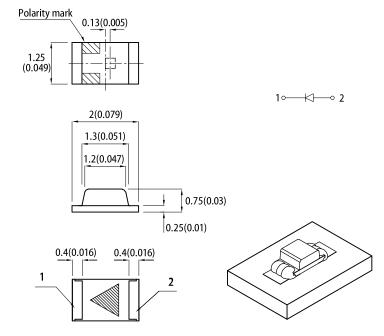
FEATURES

- 2.0 mm x 1.25 mm SMD LED, 0.75 mm thickness
- · Mechanically and spectrally matched to the phototransistor
- Package: 2000pcs / reel
- Moisture sensitivity level: 3
- · Halogen-free
- RoHS compliant

APPLICATIONS

- Infrared Illumination for cameras
- Machine vision systems
- Surveillance systems
- Industrial electronics
- IR data transmission
- Remote control





RECOMMENDED SOLDERING PATTERN

(units : mm; tolerance : ± 0.1)



Notes: 1. All dimensions are in millimeters (inches). 2. Tolerance is ±0.1(0.004") unless otherwise noted. 3. The specifications, characteristics and lechnical data described in the datasheet are subject to

change without prior notice. 4. The device has a single mounting surface. The device must be mounted according to the specifications.

SELECTION GUIDE

| Part Number | Emitting Color (Material) | Lens Type | Po (mW/sr) @ 20mA ^[2] | | Viewing Angle ^[1] | |
|-----------------|------------------------------|-------------|-------------------------------------|------|------------------------------|--|
| | | | Min. | Тур. | 201/2 | |
| APT2012SF4C-PRV | Infrared (GaAIAs) | Water Clear | 0.8 | 1.5 | 160° | |

Notes

All 2 is the angle from optical centerline where the luminous intensity is 1/2 of the optical peak value.
 Radiant Intensity / luminous flux: +/-15%.
 Radiant intensity value is traceable to CIE127-2007 standards.

Kingbright

ELECTRICAL / OPTICAL CHARACTERISTICS at T_A=25°C

| Parameter | Cumula al | Emitting Color | Value | | Unit |
|--|-------------------------------|----------------|-----------|-----|-------|
| Parameter | Symbol | Emitting Color | Typ. Max. | | |
| Wavelength at Peak Emission I_F = 20mA | λ_{peak} | Infrared | 880 | - | nm |
| Spectral Bandwidth at 50% Φ REL MAX I _F = 20mA | Δλ | Infrared | 50 | - | nm |
| Capacitance | С | Infrared | 90 | - | pF |
| Forward Voltage I _F = 20mA | V _F ^[1] | Infrared | 1.3 | 1.6 | V |
| Reverse Current (V _R = 5V) | I _R | Infrared | - | 10 | μA |
| Temperature Coefficient of Wavelength I_F = 20mA, -10°C \leq T \leq 85°C | TC _λ | Infrared | 0.3 | - | nm/°C |
| Temperature Coefficient of $~V_F$ I_F = 20mA, -10°C \leq T \leq 85°C | TCv | Infrared | -1.3 | - | mV/°C |

Notes:

Forward voltage: ±0.1V.
 Wavelength value is traceable to CIE127-2007 standards.
 Excess driving current and / or operating temperature higher than recommended conditions may result in severe light degradation or premature failure.

| Parameter | Symbol | Value | Unit |
|--|-----------------------------------|------------|------|
| Power Dissipation | P _D | 85 | mW |
| Reverse Voltage | V _R | 5 | V |
| Junction Temperature | Tj | 125 | °C |
| Operating Temperature | T _{op} | -40 to +85 | °C |
| Storage Temperature | T _{stg} | -40 to +85 | °C |
| DC Forward Current | I _F | 50 | mA |
| Peak Forward Current | I _{FM} ^[1] | 1200 | mA |
| Electrostatic Discharge Threshold (HBM) | - | 8000 | V |
| Thermal Resistance (Junction / Ambient) | R _{th JA} ^[2] | 460 | °C/W |
| Thermal Resistance (Junction / Solder point) | R _{th JS} ^[2] | 350 | °C/W |

ABSOLUTE MAXIMUM RATINGS at T₄=25°C

Notes: 1. 1/100 Duty Cycle, 10µs Pulse Width. 2. $R_{in,JS}$, $R_{in,JS}$ Results from mounting on PC board FR4 (pad size ≥ 16 mm² per pad). 3. Relative humidity levels maintained between 40% and 60% in production area are recommended to avoid the build-up of static electricity – Ref JEDEC/JESD625-A and JEDEC/J-STD-033.

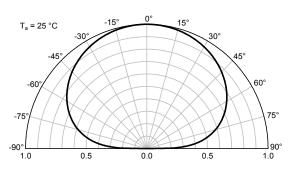
Kingbright

APT2012SF4C-PRV

TECHNICAL DATA

RELATIVE INTENSITY vs. WAVELENGTH SF4 100% T_a = 25 °C Relative Intensity (a. u.) 80% 60% 40% 20% 0% 600 650 700 750 800 850 900 950 1000 1050 Wavelength (nm)

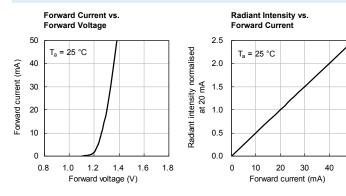
SPATIAL DISTRIBUTION



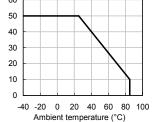
INFRARED

Permissible .

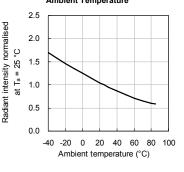
50



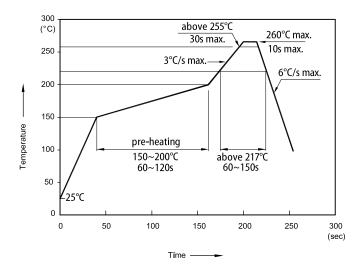
Forward Current Derating Curve 70 forward current (mA) 60



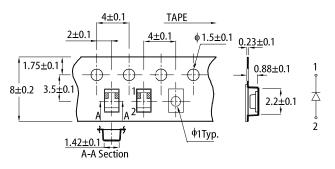
Radiant Intensity vs. Ambient Temperature



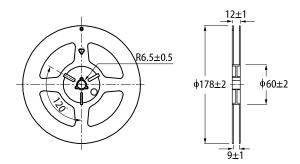
REFLOW SOLDERING PROFILE for LEAD-FREE SMD PROCESS



TAPE SPECIFICATIONS (units:mm)



REEL DIMENSION (units : mm)



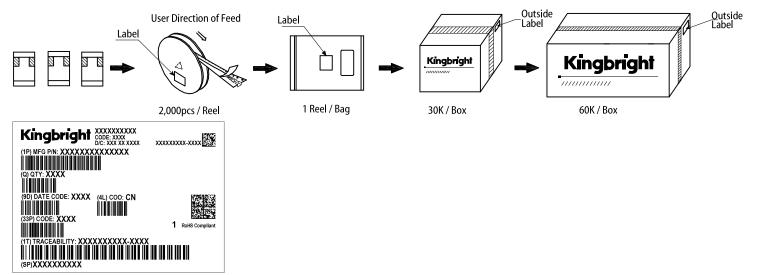
Notes

- Don't cause stress to the LEDs while it is exposed to high temperature.
 The maximum number of reflow soldering passes is 2 times.
 Reflow soldering is recommended. Other soldering methods are not recommended as they might cause damage to the product.

Kingbright

APT2012SF4C-PRV

PACKING & LABEL SPECIFICATIONS



PRECAUTIONARY NOTES

- The information included in this document reflects representative usage scenarios and is intended for technical reference only.
- The part number, type, and specifications mentioned in this document are subject to future change and improvement without notice. Before production usage customer should refer to the latest datasheet for the updated specifications. 2.
- 3.
- When using the products referenced in this document, please make sure the product is being operated within the environmental and electrical limits specified in the datasheet. If customer usage exceeds the specified limits, Kingbright will not be responsible for any subsequent issues. The information in this document applies to typical usage in consumer electronics applications. If customer's application has special reliability requirements or have life-threatening liabilities, such as automotive or medical usage, please consult with Kingbright representative for further assistance. The contents and information of this document may not be reproduced or re-transmitted without permission by Kingbright. All design applications should refer to Kingbright application notes available at https://www.KingbrightUSA.com/ApplicationNotes 4.
- 5.
- 6.